PF0031

MOS FET Power Amplifier Module for Mobile Phone

HITACHI

ADE-208-461 (Z)
1st Edition
July 1, 1996

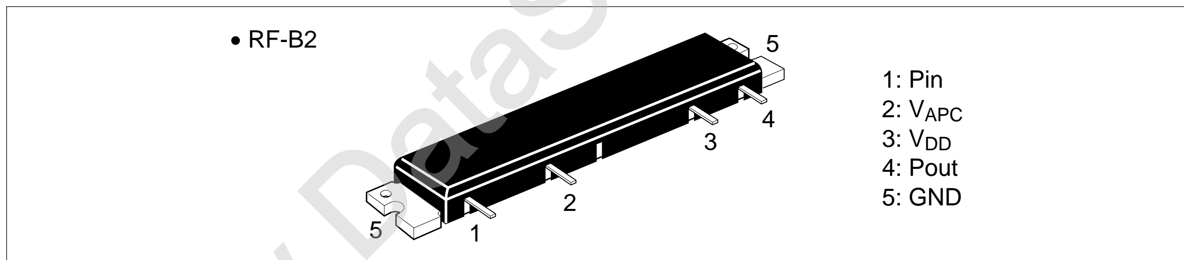
Application

PF0031: For NMT900 890 to 925 MHz

Features

- High stability: Load VSWR ≈ 20:1
- Low power control current: 400 µA
- Thin package: 5 mm t

Pin Arrangement



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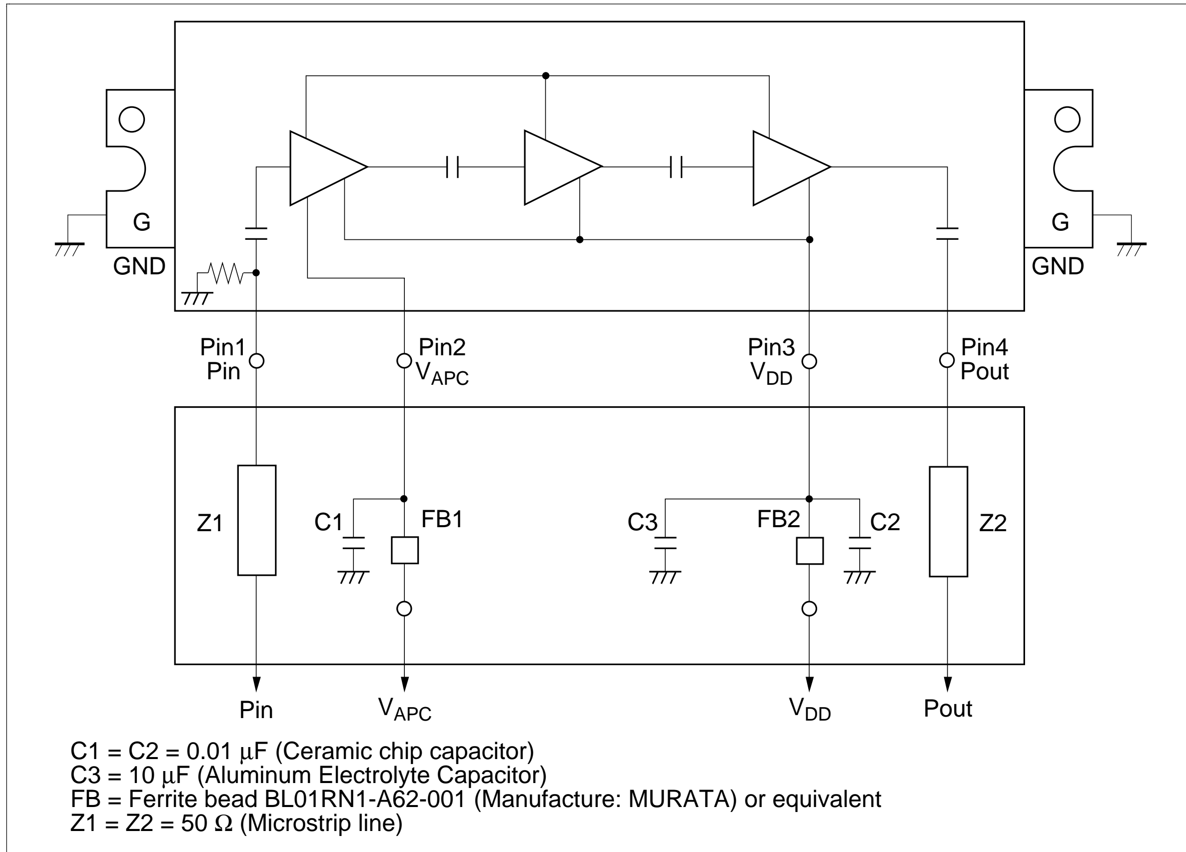
Internal Diagram and External Circuit



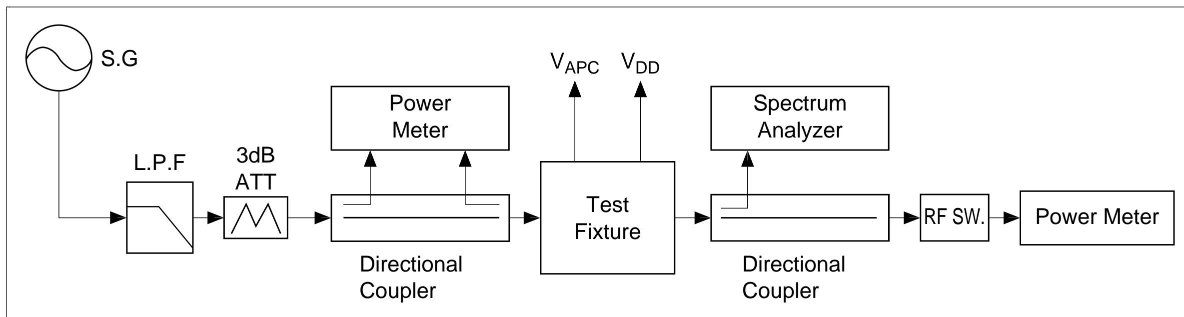
Absolute Maximum Ratings (Tc = 25°C)

Item	Symbol	Rating	Unit
Supply voltage	V_{DD}	17	V
Supply current	I_{DD}	3	A
APC voltage	V_{APC}	8	V
Input power	Pin	20	mW
Operating case temperature	Tc (op)	–30 to +100	°C
Storage temperature	Tstg	–40 to +110	°C

Electrical Characteristics (Tc = 25°C)

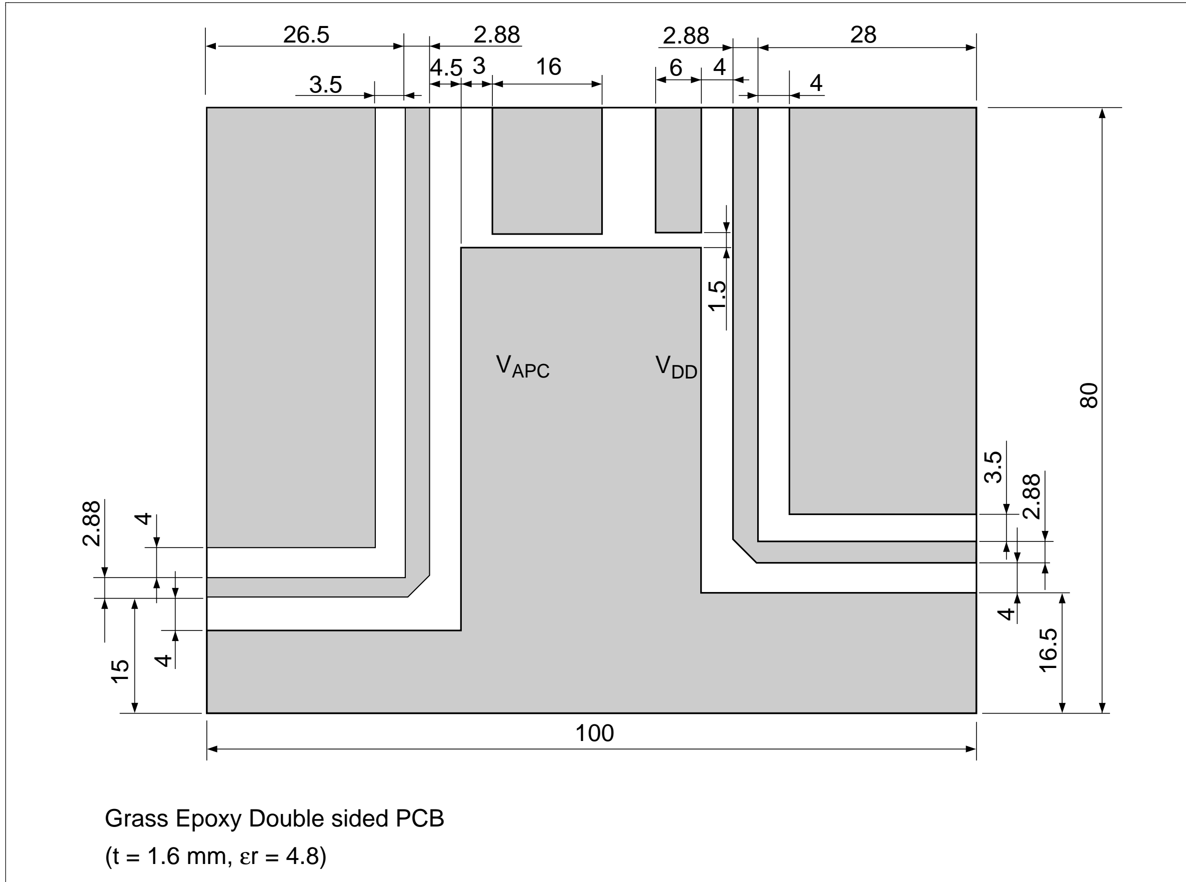
Item	Symbol	Min	Typ	Max	Unit	Test Condition
Drain cutoff current	I_{DS}	—	—	500	µA	V_{DD} = 17 V, V_{APC} = 0 V, Rg = R_L= 50 Ω
Total efficiency	η_T	35	40	—	%	Pin = 2 mW, V_{DD} = 12.5 V,
2nd harmonic distortion	2nd H.D.	—	–50	–30	dB	Pout = 6 W (at APC controlled)
3rd harmonic distortion	3rd H.D.	—	–50	–30	dB	R_L = Rg = 50 Ω
Input VSWR	VSWR (in)	—	1.5	3	—	
Output VSWR	VSWR (out)	—	1.5	—	—	
Stability	—	No parasitic oscillation			—	Pin = 2 mW, V_{DD} = 12.5 V, Pout = 6 W (at APC controlled), R_L = Rg = 50 Ω, Output VSWR = 20:1 All phases, t = 20sec

Test System Diagram



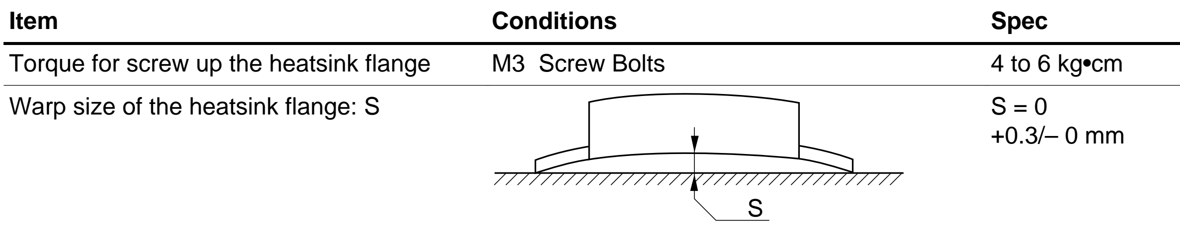
Test Fixture Pattern

Unit: mm



Grass Epoxy Double sided PCB
(t = 1.6 mm, εr = 4.8)

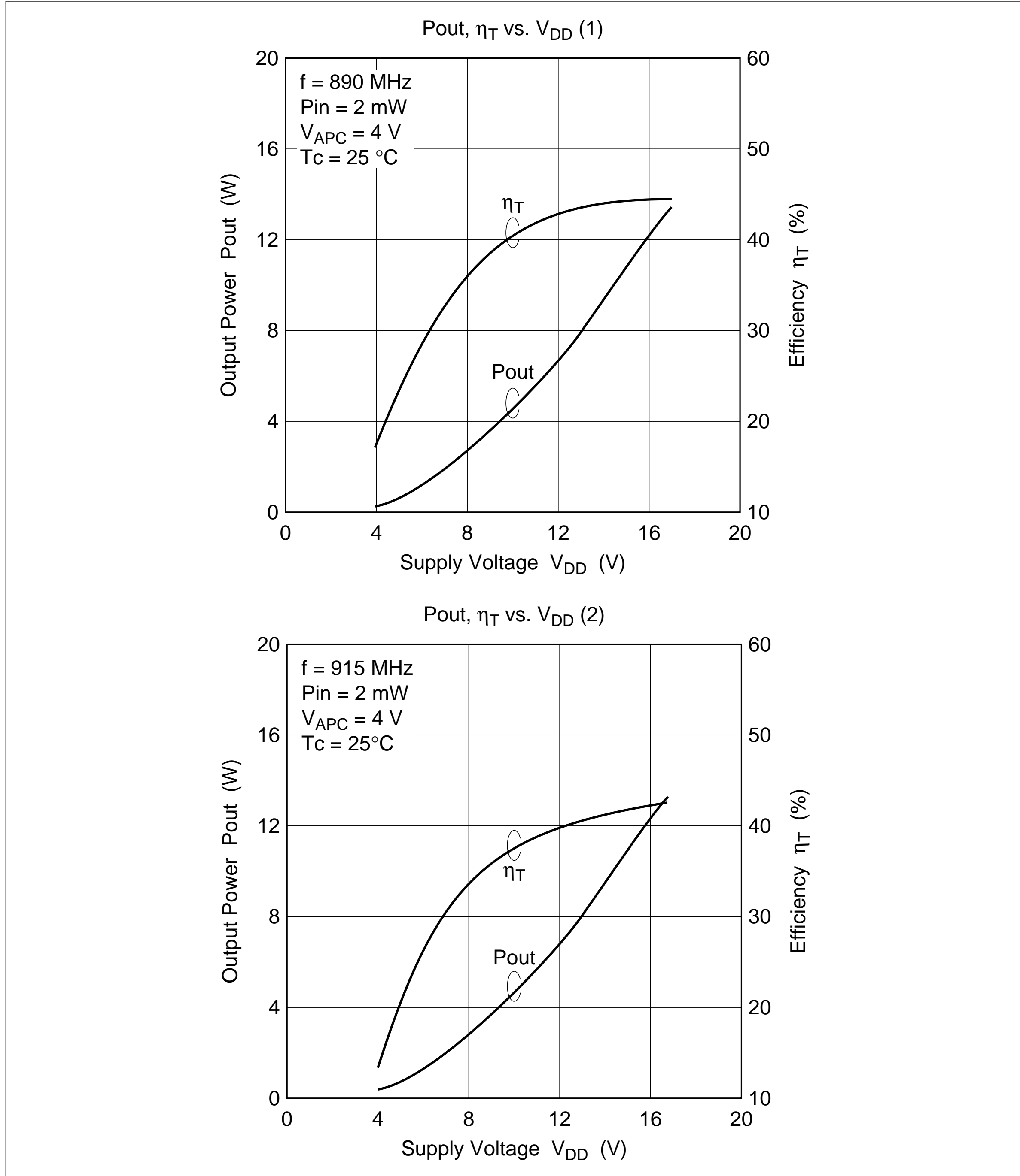
Mechanical Characteristics

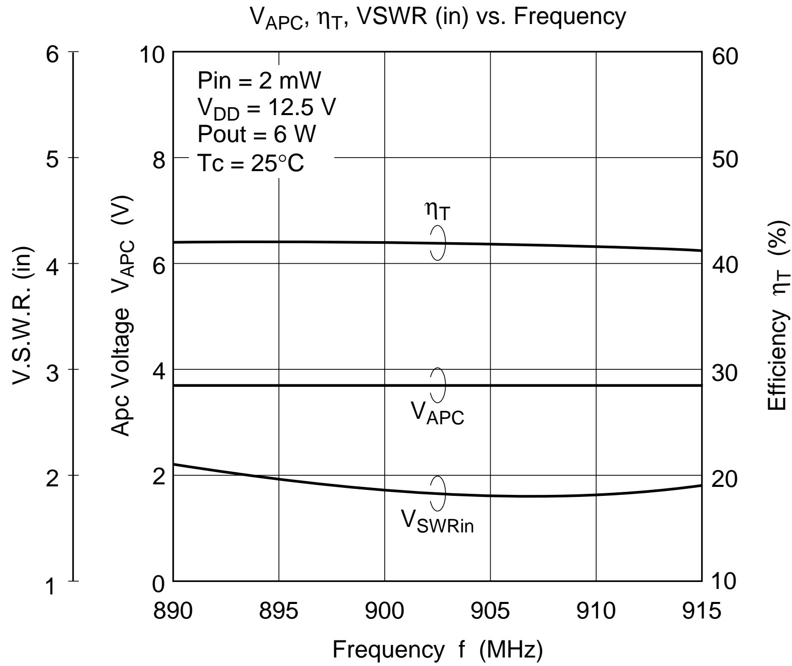
Item	Conditions	Spec
Torque for screw up the heatsink flange	M3 Screw Bolts	4 to 6 kg•cm
Warp size of the heatsink flange: S		S = 0 +0.3/– 0 mm

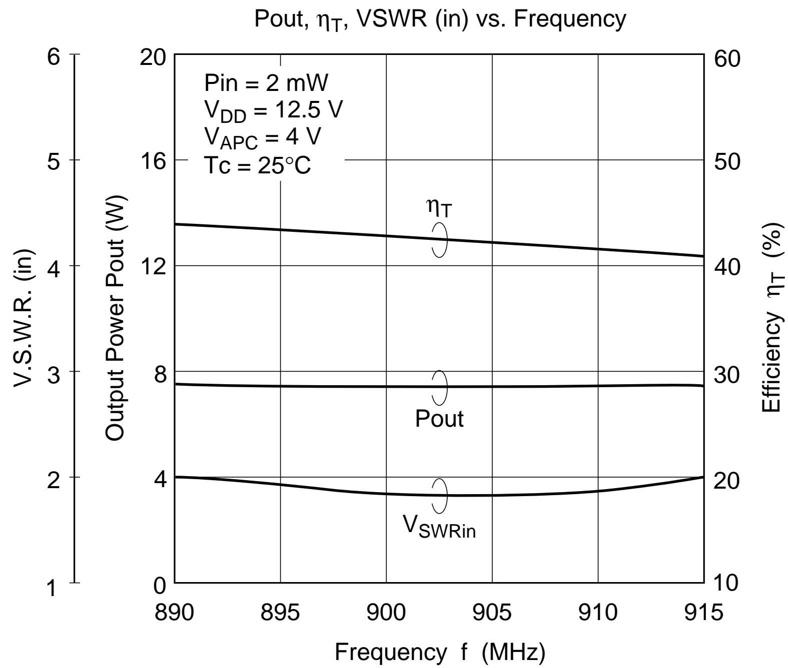
Note for Use

- Unevenness and distortion at the surface of the heatsink attached module should be less than 0.05 mm.
- It should not be existed any dust between module and heatsink.
- MODULE should be separated from PCB less than 1.5 mm.
- Soldering temperature and soldering time should be less than 230°C, 10 sec.
  (Soldering position spaced from the root point of the lead frame: 2 mm)
- Recommendation of thermal joint compounds is TYPE G746.
  (Manufacturer: Shin-Etsu Chemical, Co., Ltd.)
- To protect devices from electro-static damage, soldering iron, measuring-equipment and human body etc. should be grounded.
- Torque for screw up the heatsink flange should be 4 to 6 kg · cm with M3 screw bolts.
- Don't solder the flange directly.
- It should make the lead frame as straight as possible.
- The module should be screwed up before lead soldering.
- It should not be given mechanical and thermal stress to lead and flange of the module.
- When the external parts (Isolator, Duplexer, etc.) of the module are changed, the electrical characteristics should be evaluated enough.
- Don't washing the module except lead pins.
- To get good stability, ground impedance between the module GND flange and PCB GND pattern should be designed as low as possible.

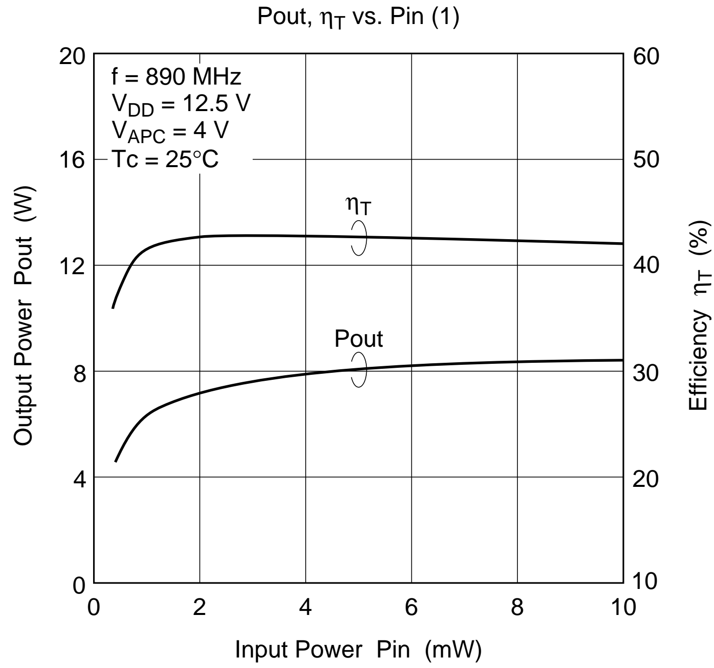
Characteristics Curve



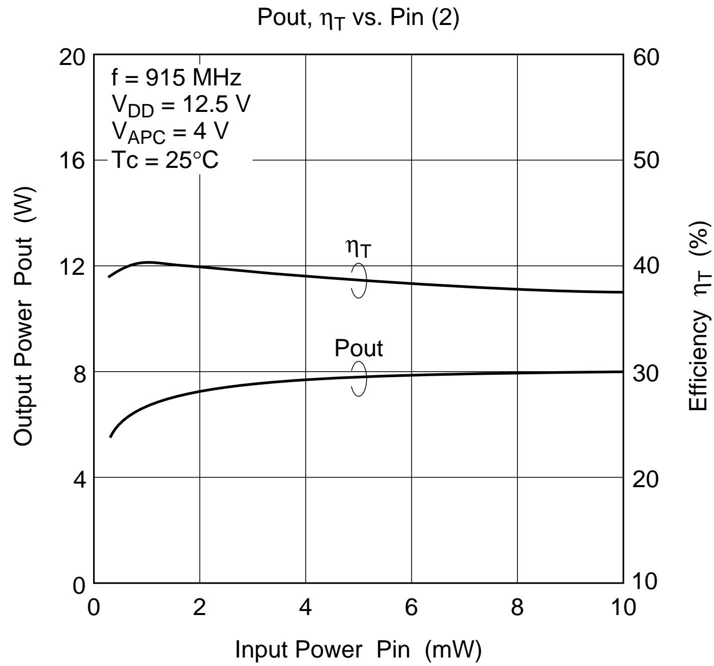

VAPC, ηT, VSWR (in) vs. Frequency
Pin = 2 mW
VDD = 12.5 V
Pout = 6 W
Tc = 25°C
ηT
VAPC
VSWRin
V.S.W.R. (in)
Apc Voltage VAPC (V)
Efficiency ηT (%)
Frequency f (MHz)
6
5
4
3
2
1
10
8
6
4
2
0
60
50
40
30
20
10
890
895
900
905
910
915

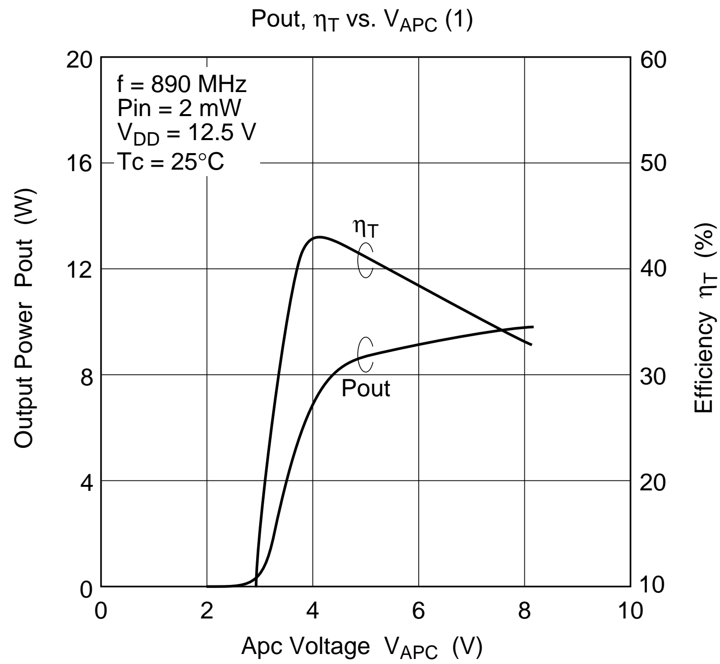

Pout, ηT, VSWR (in) vs. Frequency
Pin = 2 mW
VDD = 12.5 V
VAPC = 4 V
Tc = 25°C
ηT
Pout
VSWRin
V.S.W.R. (in)
Output Power Pout (W)
Efficiency ηT (%)
Frequency f (MHz)
6
5
4
3
2
1
20
16
12
8
4
0
60
50
40
30
20
10
890
895
900
905
910
915

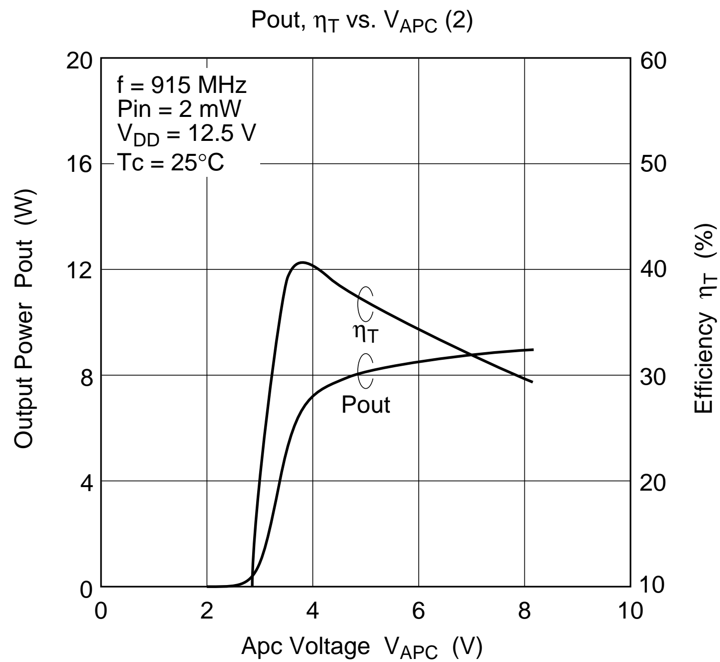
Pout, η_T vs. Pin (1)

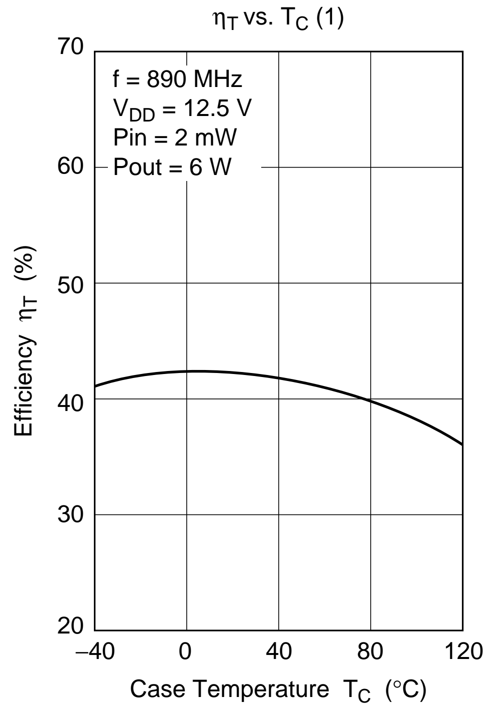


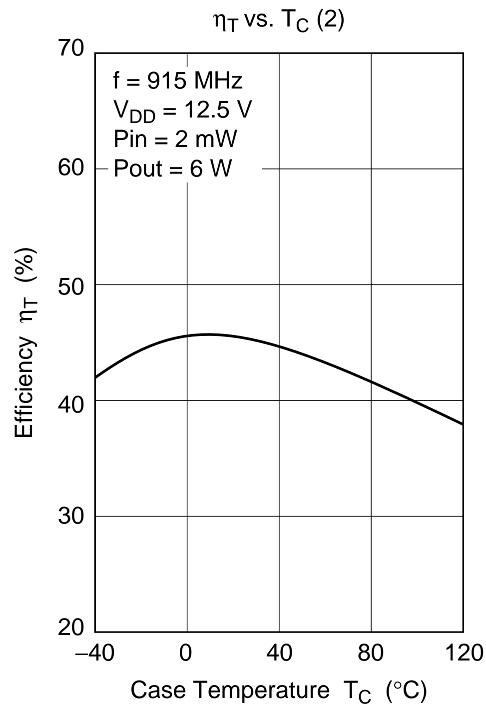
Pout, η_T vs. Pin (2)



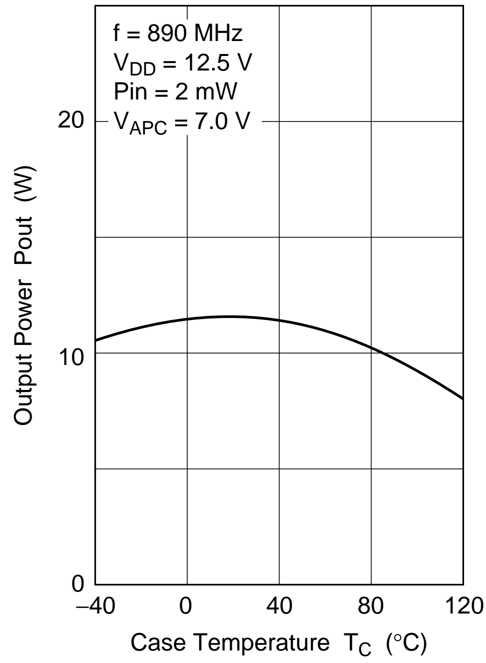

Pout, ηT vs. VAPC (1)
f = 890 MHz
Pin = 2 mW
VDD = 12.5 V
Tc = 25°C
ηT
Pout
Output Power Pout (W)
Efficiency ηT (%)
Apc Voltage VAPC (V)
0
2
4
6
8
10
0
4
8
12
16
20
10
20
30
40
50
60


Pout, ηT vs. VAPC (2)
f = 915 MHz
Pin = 2 mW
VDD = 12.5 V
Tc = 25°C
ηT
Pout
Output Power Pout (W)
Efficiency ηT (%)
Apc Voltage VAPC (V)
0
2
4
6
8
10
0
4
8
12
16
20
10
20
30
40
50
60

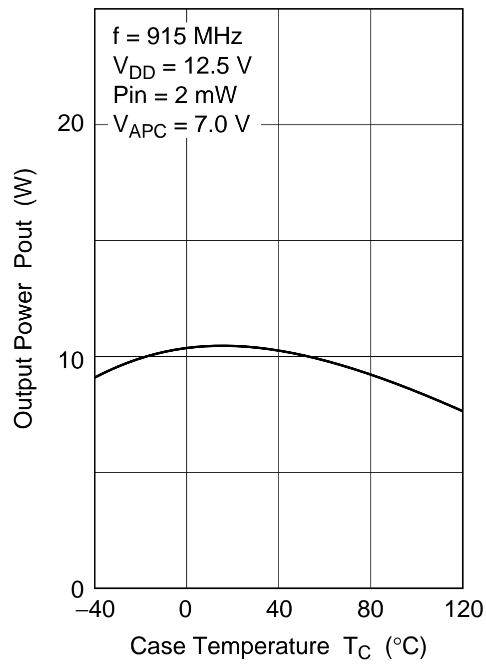

ηT vs. TC (1)
f = 890 MHz
VDD = 12.5 V
Pin = 2 mW
Pout = 6 W
70
60
50
40
30
20
–40
0
40
80
120
Efficiency ηT (%)
Case Temperature TC (°C)


ηT vs. TC (2)
f = 915 MHz
VDD = 12.5 V
Pin = 2 mW
Pout = 6 W
70
60
50
40
30
20
–40
0
40
80
120
Efficiency ηT (%)
Case Temperature TC (°C)

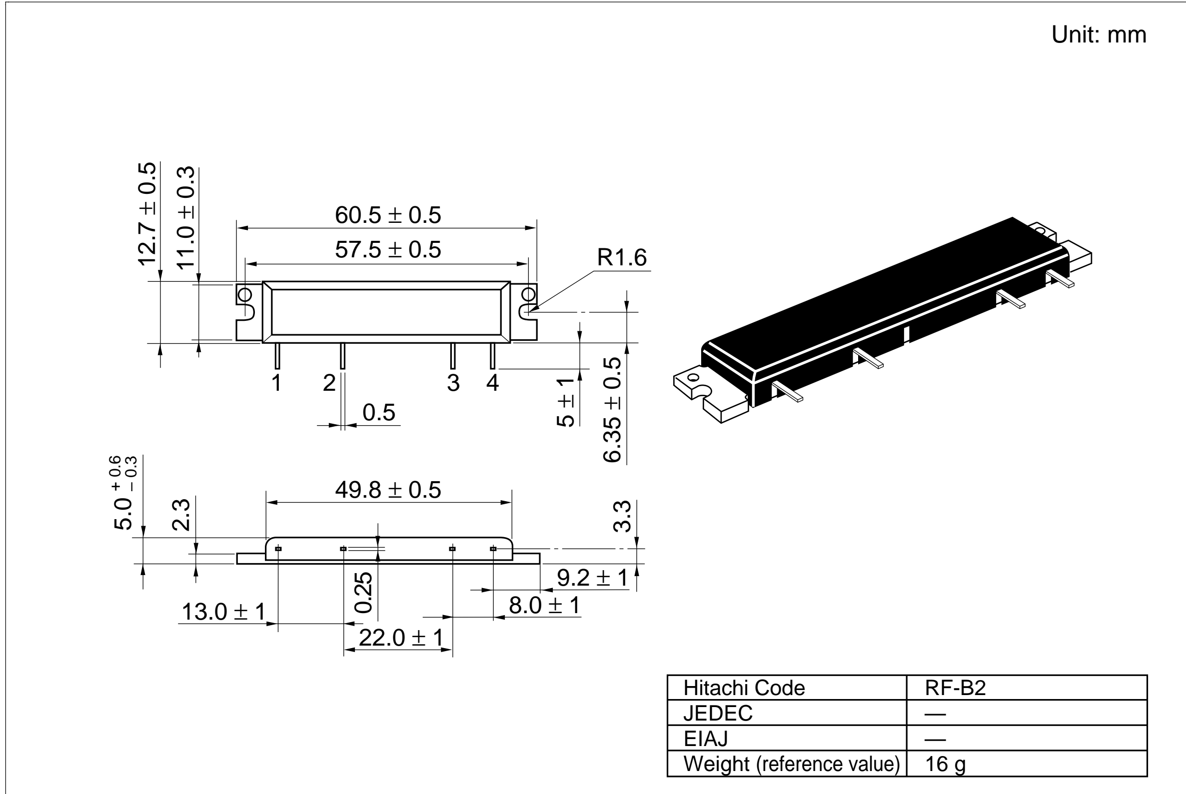
Pout vs. T_C (1)



Pout vs. T_C (2)



Package Dimensions



Hitachi Code	RF-B2
JEDEC	—
EIAJ	—
Weight (reference value)	16 g

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